## NSN 5961-00-681-9914

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-681-9914 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, emitter-to-base, collector open and 55.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: